

IRG7CH30K10EF Information


For Reference Only

Part Number [IRG7CH30K10EF](#)
Manufacturer Infineon Technologies
Category Discrete Semiconductor Products
[Transistors - IGBTs - Single](#)
Description IGBT CHIP WAFER
Package Die
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IRG7CH30K10EF Specifications

Manufacturer Part Number	IRG7CH30K10EF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	Trench
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	10A
Current - Collector Pulsed (Icm)	-
Vce(on) (Max) @ Vge, Ic	2.56V @ 15V, 10A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	4.8nC
Td (on/off) @ 25°C	10ns/90ns
Test Condition	600V, 10A, 22 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-40°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die

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IRG7CH30K10EF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRG7CH30K10EF Payment Methods



IRG7CH30K10EF Shipping Methods



If you have any question about IRG7CH30K10EF, please do not hesitate to contact us!

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